

DESCRIPTION

The CENTRAL SEMICONDUCTOR 2N5814 Series types are epoxy molded Complementary Silicon Small Signal Transistors manufactured by the epitaxial Planar process designed for general purpose amplifier applications where a high collector current rating is required.

MAXIMUM RATINGS ($T_A=25^{\circ}C$ unless otherwise noted)

	SYMBOL		UNIT
Collector Base Voltage	V _{CBO}	50	V
Collector Emitter Voltage	VCES	50	V
Collector Emitter Voltage	VCEO	40	V
Emitter Base Voltage	VEBO	5.0	٧
Collector Current	IC	750	mA
Collector Current (PEAK)	ICM	1000	mA
Power Dissipation	PD	625	mW
Power Dissipation $(T_{C}=25^{\circ}C)$	PD	1500	mW
Operating and Storage Junction Temperature	Tj,Tstg	-65 TO +150	°C

ELECTRICAL CHARACTERISTICS ($T_A=25^{\circ}C$ unless otherwise noted)

SYMBOL TCBO	TEST CONDITIONS VCB=25V	MIN	MAX 100	UNIT nA
I _{CBO}	$V_{CB}=25V$, $T_{A}=100^{\circ}C$		15	μA
IEBO	V _{EB} =5.0V		10	μA
BVCES	$I_{c}=10\mu A$	50		ี V
BVCEO	Ič=10mA	40		v
BVEBO	$I_{F}=10\mu A$	5.0		V
V _{CE} (SAT)	I _C =500mA, I _B =50mA		0.75	V
VBE(SAT)	$I_{C}=500 \text{mA}$, $I_{B}=50 \text{mA}$		1.2	V
VBE(ON)	$V_{CE}=2.0V, I_{C}=500mA$	0.60	1.1	V
hFE	$V_{CF}=2.0V$, $I_{C}=2.0mA(2N5814,2N5815)$	60	120	
h _{FE}	$V_{CF}=2.0V$, $I_{C}=2.0mA(2N5816, 2N5817)$	100	200	
h _{FE}	VCE=2.0V, Ic=2.0mA(2N5818,2N5819)	150	300	
hFE	Vce=2.0V, Ic=500mA(2N5814,2N5815)	20	-	
h _{FE}	V _{CF} =2.0V, I _C =500mA(2N5816,2N5817)	25	-	
hFE	$V_{CF}=2.0V$, $I_{C}=500mA(2N5818,2N5819)$	25	-	
fŢ	$V_{CF}=2.0V$, $I_{C}=50mA$, f=20MHz(2N5814,2N5815)	100		MHz
	$V_{CE}=2.0V$, $I_{C}=50mA$, f=20MHz(2N5816,2N5817)	1201		MHz
f _T fT	$V_{CE}=2.0V$, $I_{C}=50mA$, f=20MHz(2N5818,2N5819)	135		MHz
C _{ob}	V _{CB} =10V, f=1.0MHz		15	pF
Cib	$V_{EB}=0.5V$, f=1.0MHz		55	pF



145 Adams Avenue Hauppauge, NY 11788 USA Tel: (631) 435-1110 • Fax: (631) 435-1824 www.centralsemi.com

OUTSTANDING SUPPORT AND SUPERIOR SERVICES

PRODUCT SUPPORT

Central's operations team provides the highest level of support to insure product is delivered on-time.

- Supply management (Customer portals)
- Inventory bonding
- · Consolidated shipping options

DESIGNER SUPPORT/SERVICES

Central's applications engineering team is ready to discuss your design challenges. Just ask.

- Free quick ship samples (2nd day air)
- Online technical data and parametric search
- SPICE models
- Custom electrical curves
- Environmental regulation compliance
- Customer specific screening
- Up-screening capabilities

ss your design challenges.

· Custom product packing

- Special wafer diffusions
- PbSn plating options
- Package details
- Application notes
- · Application and design sample kits

Custom bar coding for shipments

Custom product and package development

REQUESTING PRODUCT PLATING

- 1. If requesting Tin/Lead plated devices, add the suffix "TIN/LEAD" to the part number when ordering (example: 2N2222A TIN/LEAD).
- If requesting Lead (Pb) Free plated devices, add the suffix "PBFREE" to the part number when ordering (example: 2N2222A PBFREE).

CONTACT US

Corporate Headquarters & Customer Support Team

Central Semiconductor Corp. 145 Adams Avenue Hauppauge, NY 11788 USA Main Tel: (631) 435-1110 Main Fax: (631) 435-1824 Support Team Fax: (631) 435-3388 www.centralsemi.com

Worldwide Field Representatives: www.centralsemi.com/wwreps

Worldwide Distributors: www.centralsemi.com/wwdistributors

For the latest version of Central Semiconductor's **LIMITATIONS AND DAMAGES DISCLAIMER**, which is part of Central's Standard Terms and Conditions of sale, visit: <u>www.centralsemi.com/terms</u>



Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Central Semiconductor: 2N5817 TIN/LEAD